# NSN 5961-01-030-8067

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**Inclosure Material:** 

Metal

**Overall Length:** 

0.340 inches

# **Overall Diameter:**

0.620 inches

#### **End Application:**

Anfsq111

# **Mounting Facility Quantity:**

2

# Internal Configuration:

Junction contact

# Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Unthreaded hole

# Features Provided:

Hermetically sealed case

# Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

450.0 breakdown voltage, collector-to-base, emitter open and 350.0 breakdown voltage, collector-to-emitter, base open and 9.0

breakdown voltage, emitter-to-base, collector open

# **Current Rating Per Characteristic:**

Between 4.00 amperes source cutoff current and 7.00 amperes source cutoff current

# **Power Rating Per Characteristic:**

45.0 watts small-signal input power, common-collector

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

# **Special Features:**

Junction pattern arrangement: npn

# **Terminal Type And Quantity:**

2 uninsulated wire lead and 1 case

Shelf Life:

N/a

# Unit Of Measure:

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# Demilitarization:

No

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